NSN 5961-01-123-8139



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-123-8139 **Inclosure Material:** Plastic **Overall Length:** Between 0.580 inches and 0.620 inches **Overall Height:** Between 0.110 inches and 0.135 inches Overall Width: Between 0.405 inches and 0.425 inches **End Application:** An/gsq-207v1 80058 **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-218 **Mounting Method:** Unthreaded hole **Features Provided:** Mounting hardware **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 0.50 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 3.5 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

Fiig:

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